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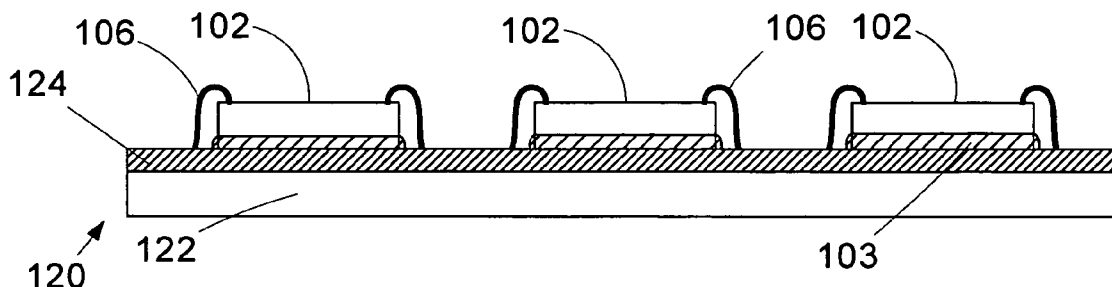
(19) **United States**(12) **Patent Application Publication****Corisis et al.**(10) **Pub. No.: US 2007/0216033 A1**(43) **Pub. Date: Sep. 20, 2007**(54) **CARRIERLESS CHIP PACKAGE FOR
INTEGRATED CIRCUIT DEVICES, AND
METHODS OF MAKING SAME****Publication Classification**(51) **Int. Cl.****H01L 23/52** (2006.01)**H01L 23/48** (2006.01)(52) **U.S. Cl.** **257/777; 257/778; 257/E23**(76) Inventors: **David J. Corisis**, Nampa, ID (US); **Lee
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(57)

ABSTRACT

Disclosed is a carrierless chip package for integrated circuit devices, and various methods of make same. In one illustrative embodiment, the device includes an integrated circuit chip comprising an exposed backside surface defining a plane, a plurality of wire bonds that are conductively coupled to the integrated circuit chip, each of the plurality of wire bonds being conductively coupled to a conductive exposed portion, a portion of the conductive exposed portion being positioned in the plane defined by the backside surface, and an encapsulant material positioned adjacent the integrated circuit chip and the plurality of wire bonds.

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HOUSTON, TX 77042 (US)**(21) Appl. No.: **11/384,734**(22) Filed: **Mar. 20, 2006**

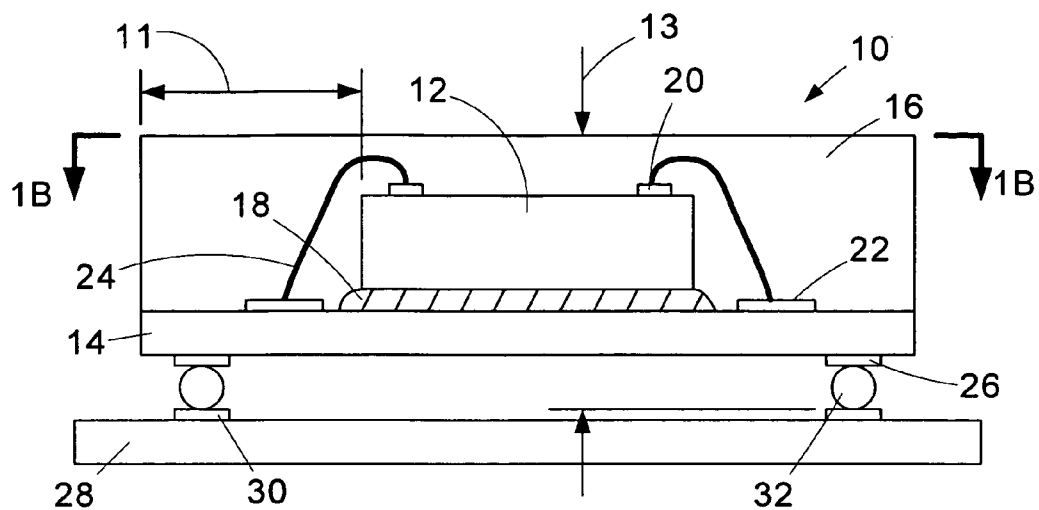


Figure 1A (Prior Art)

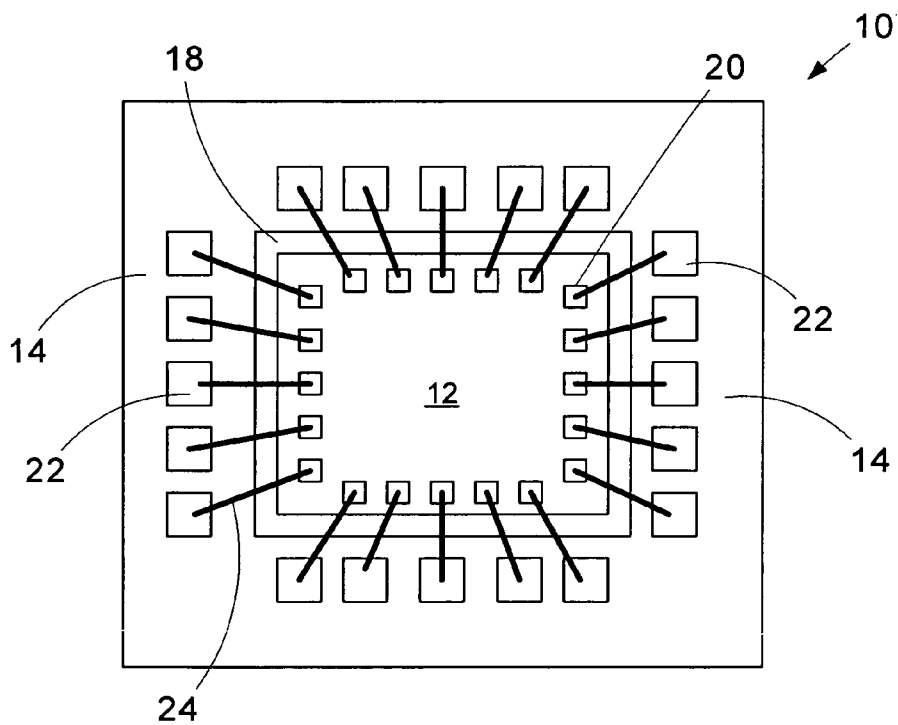
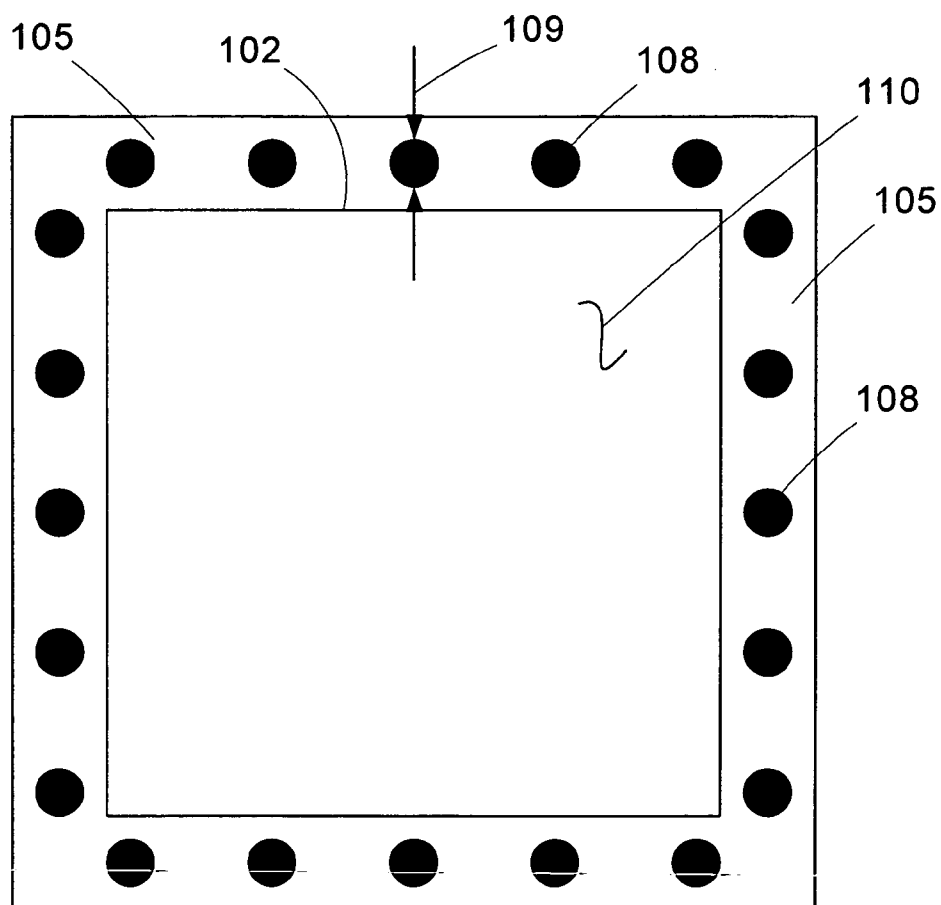
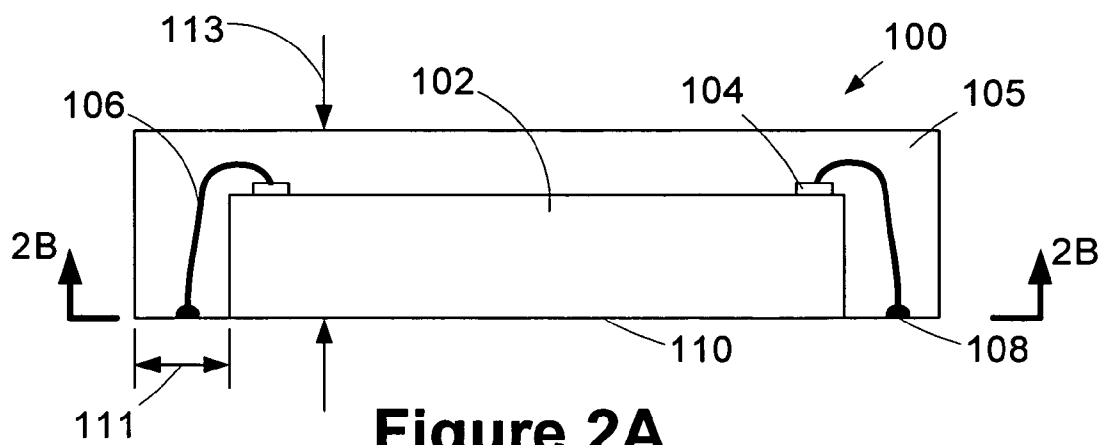


Figure 1B (Prior Art)



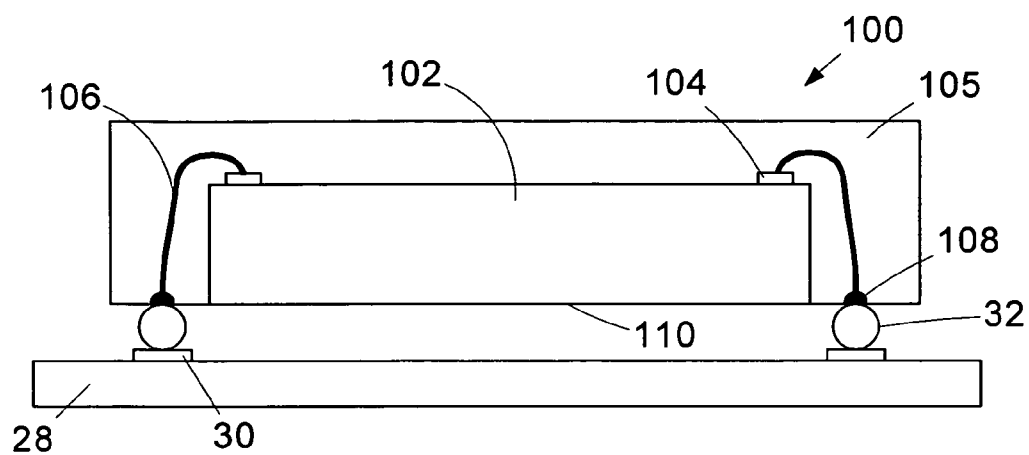


Figure 2C

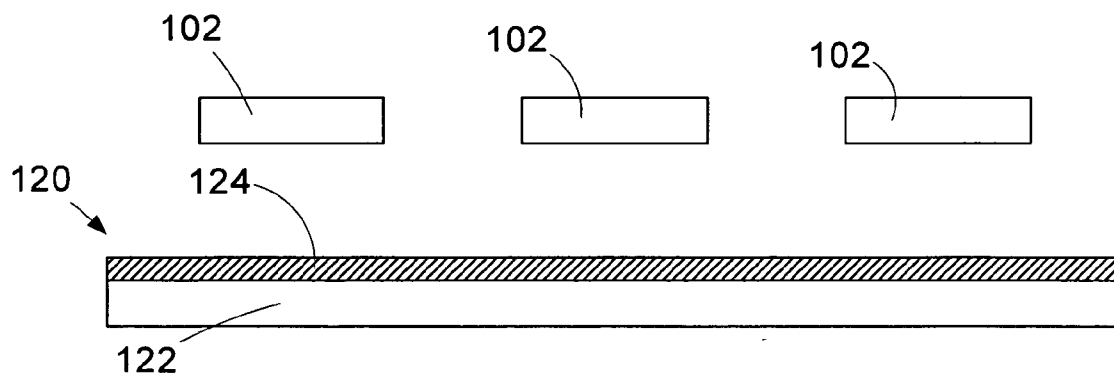


Figure 3A

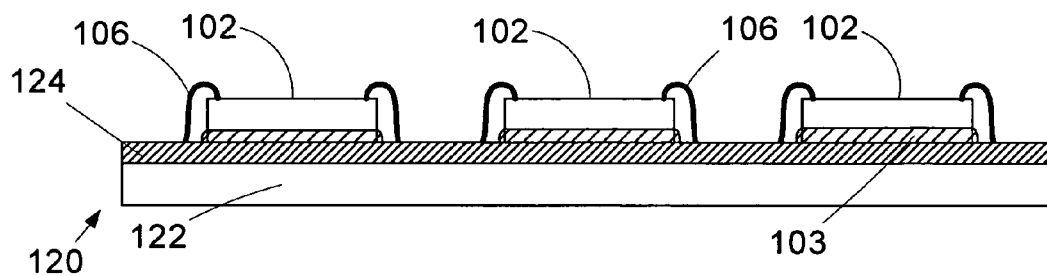


Figure 3B

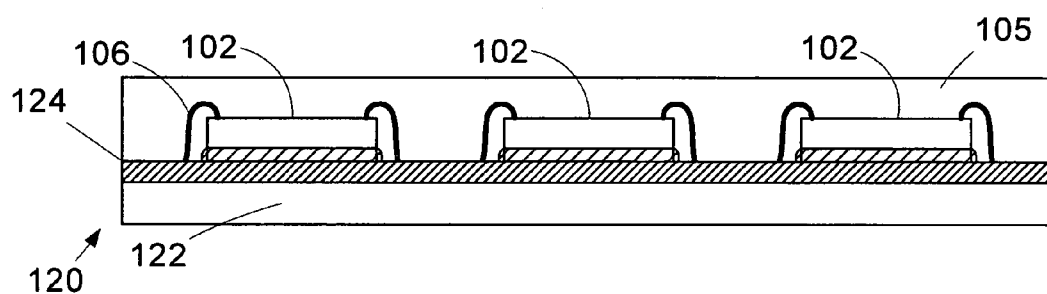


Figure 3C

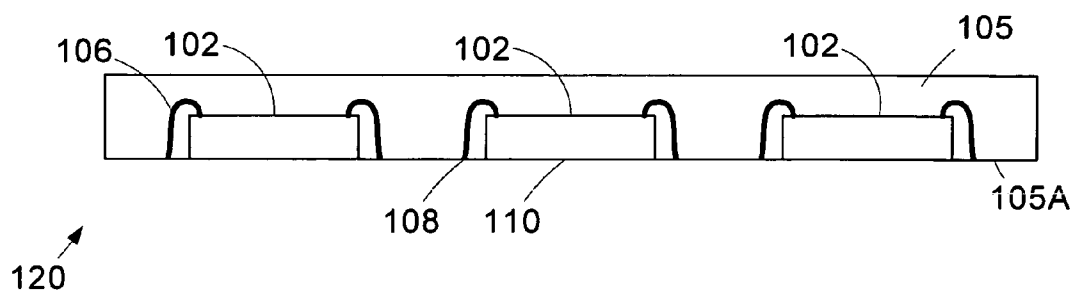


Figure 3D

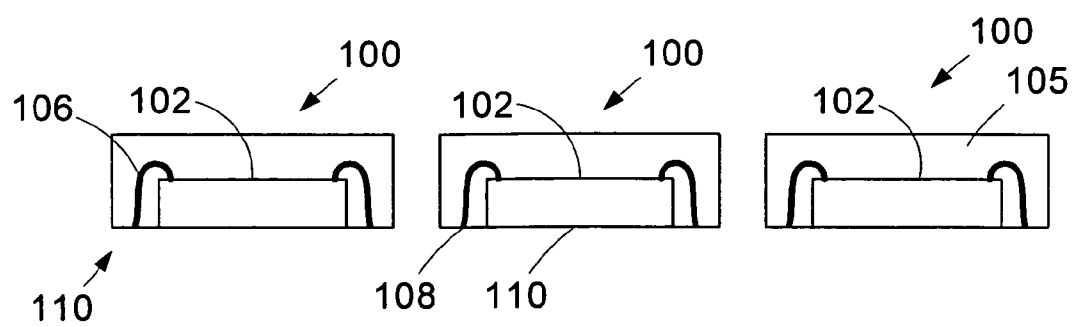


Figure 3E

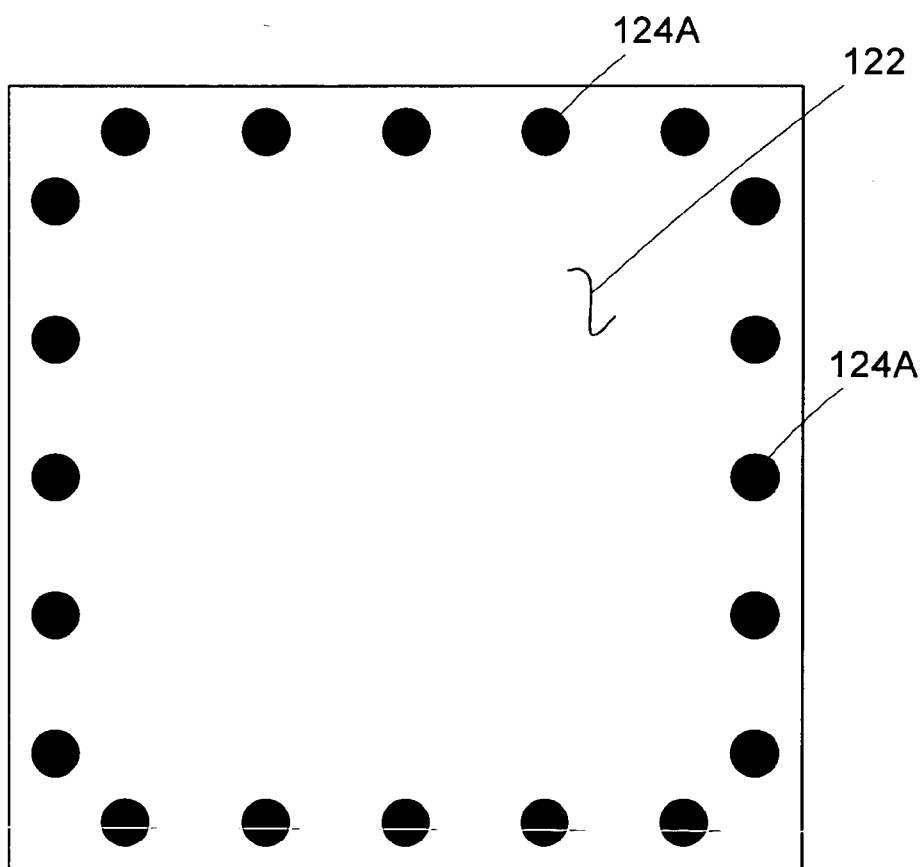


Figure 4

CARRIERLESS CHIP PACKAGE FOR INTEGRATED CIRCUIT DEVICES, AND METHODS OF MAKING SAME

BACKGROUND OF THE INVENTION

[0001] 1. Field of the Invention

[0002] The present invention generally relates to the field of packaging integrated circuit devices, and, more particularly, to a carrierless chip package for integrated circuit devices, and various methods of making same.

[0003] 2. Description of the Related Art

[0004] Microelectronic devices generally have a die (i.e., a chip) that includes integrated circuitry having a high density of very small components. In a typical process, a large number of die are manufactured on a single wafer using many different processes that may be repeated at various stages (e.g., implanting, doping, photolithography, chemical vapor deposition, plasma vapor deposition, plating, planarizing, etching, etc.). The die typically include an array of very small bond pads electrically coupled to the integrated circuitry. The bond pads are the external electrical contacts on the die through which the supply voltage, signals, etc. are transmitted to and from the integrated circuitry. The die are then separated from one another (i.e., singulated) by backgrinding and cutting the wafer. After the wafer has been singulated, the individual die are typically "packaged" to couple the bond pads to a larger array of electrical terminals that can be more easily coupled to the various power supply lines, signal lines and ground lines.

[0005] Electronic products require packaged microelectronic devices to have an extremely high density of components in a very limited space. For example, the space available for memory devices, processors, displays and other microelectronic components is quite limited in cell phones, PDAs, portable computers and many other products. As such, there is a strong drive to reduce the height of a packaged microelectronic device and the surface area or "footprint" of a microelectronic device on a printed circuit board. Reducing the size of a microelectronic device is difficult because high performance microelectronic devices generally have more bond pads, which result in larger ball/grid arrays and thus larger footprints.

[0006] FIGS. 1A-1B are, respectively, a cross-sectional and top view of an illustrative packaged integrated circuit (IC) device 10. The packaged IC device 10 is comprised of an integrated circuit chip 12 that is affixed to a carrier 14 by an adhesive material 18. The chip 12 and carrier 14 comprise a plurality of bond pads 20 and 22, respectively. A plurality of wire bonds 24 conductively couple the bond pads 20 on the chip 12 with the bond pads 22 on the carrier 14. Also depicted in FIG. 1A is a conductive structure 28, such as a printed circuit board, a motherboard, a memory module, or the like. The conductive structure 28 typically comprises a plurality of insulated traces (not shown) and a plurality of bond pads 30. In one illustrative embodiment, the chip 12 is conductively coupled to the conductive structure 28 by a plurality of solder balls 30. The chip 12 is encapsulated with a molding or epoxy compound 16.

[0007] FIG. 1B is a top view of the device 10 with the epoxy compound 16 removed. As shown therein, the bond pads 22 on the carrier 14 occupy a lot of space. The presence

of the bond pads 22 can, in some cases, cause the carrier 14 to delaminate. Such delamination can cause the chip 12 to fail or at least not perform up to its full capabilities. Moreover, the packaged IC device 10 can be relatively large due to its basic configuration, the components involved, and the manner in which it is fabricated. For example, the distance 11 between the edge of the chip 12 and the edge of the epoxy compound 16 may range from approximately 0.5-1.0 mm. The carrier 14 may have a thickness that varies from approximately 125-450 μm , depending on the application and the composition of the carrier 14. Similarly, the thickness of the epoxy compound 16 may also vary, e.g., from approximately 0.5-1.2 mm. Thus, the overall height 13 of the carrier 14 and epoxy compound 16 may range from approximately 0.40-1.65 mm.

[0008] The present invention is directed to a device and various methods that may solve, or at least reduce, some or all of the aforementioned problems.

SUMMARY OF THE INVENTION

[0009] The following presents a simplified summary of the invention in order to provide a basic understanding of some aspects of the invention. This summary is not an exhaustive overview of the invention. It is not intended to identify key or critical elements of the invention or to delineate the scope of the invention. Its sole purpose is to present some concepts in a simplified form as a prelude to the more detailed description that is discussed later.

[0010] The present invention is generally directed to a carrierless chip package for integrated circuit devices, and various methods of making same. In one illustrative embodiment, the device comprises an integrated circuit chip comprising an exposed backside surface defining a plane, a plurality of wire bonds that are conductively coupled to the integrated circuit chip, each of the plurality of wire bonds being conductively coupled to a conductive exposed portion, a portion of the conductive exposed portion being positioned in the plane defined by the backside surface, and an encapsulant material positioned adjacent the integrated circuit chip and the plurality of wire bonds.

[0011] In another illustrative embodiment, the device comprises an integrated circuit chip comprising an exposed backside surface defining a plane, a plurality of wire bonds that are conductively coupled to the integrated circuit chip, each of the plurality of wire bonds being conductively coupled to a conductive exposed portion, a portion of the conductive exposed portion being positioned in the plane defined by the backside surface, and an encapsulant material positioned adjacent the integrated circuit chip and the plurality of wire bonds, the encapsulant material comprising a bottom surface that is positioned substantially in the plane, wherein a distance from a side of the integrated circuit chip to a side of the encapsulant material ranges from approximately 0.1-0.4 mm.

[0012] In yet another illustrative embodiment, the device comprises an integrated circuit chip comprising an exposed backside surface defining a plane and a plurality of wire bonds that are conductively coupled to the integrated circuit chip, each of the plurality of wire bonds being conductively coupled to a conductive exposed portion, a portion of the conductive exposed portion being positioned in the plane defined by the backside surface, wherein the exposed con-

ductive portions lying in the plane have a substantially rounded configuration. The device further comprises an encapsulant material positioned adjacent the integrated circuit chip and the plurality of wire bonds and a conductive structure that is conductively coupled to the exposed conductive portions.

[0013] In one illustrative embodiment, the method comprises positioning an integrated circuit chip adjacent a sacrificial structure comprising a conductive portion, the integrated circuit chip comprising a backside surface, attaching a plurality of wire bonds to the integrated circuit chip, attaching the plurality of wire bonds to the conductive portion of the sacrificial structure to thereby define a conductive portion coupled to each of the wire bonds, forming an encapsulant material adjacent the integrated circuit chip, the wire bonds and the sacrificial structure, and removing the sacrificial structure to thereby expose the backside surface of the integrated circuit chip and at least a portion of the conductive portion that is conductively coupled to each of the plurality of wire bonds.

[0014] In another illustrative embodiment, the method comprises positioning an integrated circuit chip adjacent a sacrificial structure comprising a conductive layer, the integrated circuit chip comprising a backside surface, attaching a plurality of wire bonds to the integrated circuit chip and to the conductive layer of the sacrificial structure to thereby define a conductive portion coupled to each of the wire bonds, forming an encapsulant material adjacent the integrated circuit chip, the wire bonds and the conductive layer of the sacrificial structure, and performing a planarization process to remove the sacrificial structure to thereby expose the backside surface of the integrated circuit chip and at least a portion of the conductive portion conductively coupled to each of the plurality of wire bonds.

[0015] In yet another illustrative embodiment, the method comprises positioning an integrated circuit chip adjacent a sacrificial structure comprising a plurality of spaced-apart conductive structures, the integrated circuit chip comprising a backside surface, attaching each of a plurality of wire bonds to the integrated circuit chip and to one of the spaced-apart conductive structures of the sacrificial structure to thereby define a conductive portion coupled to each of the wire bonds, forming an encapsulant material adjacent the integrated circuit chip, the wire bonds and the sacrificial structure, and performing a planarization process to remove the sacrificial structure to thereby expose the backside surface of the integrated circuit chip and at least a portion of the conductive portion conductively coupled to each of the plurality of wire bonds.

BRIEF DESCRIPTION OF THE DRAWINGS

[0016] The invention may be understood by reference to the following description taken in conjunction with the accompanying drawings, in which like reference numerals identify like elements, and in which:

[0017] FIGS. 1A-1B depict an illustrative prior art packaged integrated circuit device;

[0018] FIGS. 2A-2C are various views of a packaged integrated circuit device in accordance with various aspects of the present invention;

[0019] FIGS. 3A-3E are various views of one illustrative method of forming the device shown in FIGS. 2A-2C; and

[0020] FIG. 4 depicts an alternative embodiment of the conductive portion of the sacrificial structure.

[0021] While the invention is susceptible to various modifications and alternative forms, specific embodiments thereof have been shown by way of example in the drawings and are herein described in detail. It should be understood, however, that the description herein of specific embodiments is not intended to limit the invention to the particular forms disclosed, but on the contrary, the intention is to cover all modifications, equivalents, and alternatives falling within the spirit and scope of the invention as defined by the appended claims.

DETAILED DESCRIPTION OF THE INVENTION

[0022] Illustrative embodiments of the invention are described below. In the interest of clarity, not all features of an actual implementation are described in this specification. It will of course be appreciated that in the development of any such actual embodiment, numerous implementation-specific decisions must be made to achieve the developers' specific goals, such as compliance with system-related and business-related constraints, which will vary from one implementation to another. Moreover, it will be appreciated that such a development effort might be complex and time-consuming, but would nevertheless be a routine undertaking for those of ordinary skill in the art having the benefit of this disclosure.

[0023] The present invention will now be described with reference to the attached figures. Various regions and structures of a packaged integrated circuit device are depicted in the drawings. For purposes of clarity and explanation, the relative sizes of the various features depicted in the drawings may be exaggerated or reduced as compared to the size of those features or structures on real-world packaged devices. Nevertheless, the attached drawings are included to describe and explain illustrative examples of the present invention. The words and phrases used herein should be understood and interpreted to have a meaning consistent with the understanding of those words and phrases by those skilled in the relevant art. No special definition of a term or phrase, i.e., a definition that is different from the ordinary and customary meaning as understood by those skilled in the art, is intended to be implied by consistent usage of the term or phrase herein. To the extent that a term or phrase is intended to have a special meaning, i.e., a meaning other than that understood by skilled artisans, such a special definition will be explicitly set forth in the specification in a definitional manner that directly and unequivocally provides the special definition for the term or phrase.

[0024] FIGS. 2A-2C depict one illustrative embodiment of a packaged integrated circuit (IC) device **100** in accordance with one aspect of the present invention. As shown in FIG. 2A, the device **100** comprises an integrated circuit chip (IC chip) **102**, a plurality of bond pads **104**, a plurality of wire bonds **106**, each of which are conductively coupled to an exposed conductive portion **108**. Also depicted in FIG. 2A is the exposed backside **110** of the IC chip **102**. An encapsulant material **105**, e.g., an epoxy or molding material, encapsulates the IC chip **102** except for the exposed backside surface **110**. FIG. 2B is a bottom view of the device **100**. As shown therein, the conductive portions **108** are positioned in the

encapsulant material **105** around the perimeter of the IC chip **102**. In the illustrative embodiment depicted in FIGS. 2A-2C, the exposed conductive portions **108** are on substantially the same plane as the exposed backside **110** of the IC chip **102**. Moreover, in one illustrative embodiment, the exposed conductive portions **108** may have a generally circular cross-sectional configuration and a diameter **109** of approximately 16-80 μm .

[0025] FIG. 2C is one illustrative example that depicts how the device **100** may be conductively coupled to a conductive structure **28**. The conductive structure **28** may be any type of structure to which it is desired to operatively couple an integrated circuit device, e.g., a printed circuit board, a silicon interposer, a motherboard, flex tape, a memory module, etc. As shown therein, the device **100** may be operatively coupled to the conductive structure **28** by a plurality of solder balls **32** that are conductively coupled to the exposed conductive portions **108** and the bond pads **30** on the conductive structure **28**. As will be recognized by those skilled in the art after a complete reading of the present application, the device **100** may be conductively coupled to the conductive structure **28** by a variety of known techniques.

[0026] As will be recognized by those skilled in the art after a complete reading of the present application, the packaged device **100** may be employed with any type of IC chip **102**, e.g., memory chips, microprocessors, ASICs, etc. Additionally, the precise shape, location and material of the illustrative bond pads **104** and wire bonds **106** may vary depending upon the particular application. Thus, the illustrative embodiment depicted herein should not be considered a limitation of the present invention.

[0027] FIGS. 3A-3E depict one illustrative method of forming the packaged IC device **100**. FIG. 3A depicts a plurality of singulated IC chips **102** that are ready to be packaged. The IC chips **102** have been manufactured and singulated using any of a variety of known processing techniques. Initially, as indicated in FIG. 3B, the IC chips **102** will be attached to a sacrificial structure **120** using, for example, an adhesive material **103** or adhesive tape. The sacrificial structure **120** comprises at least some conductive material to which the wire bonds **106** will be attached, as described more fully below. In the illustrative embodiment depicted in FIG. 3A, the sacrificial structure **120** comprises a substrate **122** and a layer of conductive material **124**, e.g., a metal such as aluminum. In one embodiment, the substrate **122** is comprised of a ceramic material and it may have a thickness of approximately 0.135-0.5 mm. The substrate **122** may also be comprised of other materials, such as an organic laminate, polymer, polyester, silicon, etc. The layer of conductive material **124** may be deposited by a variety of known processes, e.g., sputter deposition, and it may have a thickness of approximately 0.1-30 μm . In the illustrative embodiment depicted in FIG. 3A, the conductive portion of the sacrificial structure **120** takes the illustrative form of the conductive layer **124**. However, other forms are also possible. For example, as shown in FIG. 4, the conductive portion of the sacrificial structure **120** may take the form of a plurality of spaced-apart conductive structures **124A** that correspond in location to the conductive end portions **108** of the device **100**. The spaced-apart conductive region **124A** may be of any desired shape, i.e., rectangular, rounded, etc. Other structures are also possible.

[0028] Next, as indicated in FIG. 3B, the wire bonds **106** are attached to the IC chips **102** and the conductive portion of the sacrificial structure **120**, e.g., the illustrative conductive layer **124**. The wire bonds **106** may be comprised of a variety of materials, e.g., gold, aluminum, copper, etc., and they may be attached to the IC chip **102** and the conductive layer **124** using a variety of known techniques. Attaching the wire bonds **106** to the conductive portion of the sacrificial structure **120** results in the formation of the conductive end portions **108**. Thus, depending on the particular materials of construction of the wire bond **106** and the conductive portion of the sacrificial structure **120**, e.g., the conductive layer **124**, the conductive end portions **108** may comprise a combination of such materials.

[0029] Then, as shown in FIG. 3C, an encapsulant **105**, e.g., an epoxy material or molding compound, is formed around the IC chips **102**. The encapsulant **105** may be comprised of a variety of known materials, such as epoxy, liquid encapsulant, epoxy mold compound, a powder, etc., and it may be applied or formed around the IC chips **102** using a variety of known techniques.

[0030] As shown in FIG. 3D, one or more process operations are then performed to remove the sacrificial structure **120** thereby exposing the backside **110** of the IC chips **102** and the exposed conductive portions **108**. The sacrificial structure **120** may be removed by a variety of techniques. In one illustrative embodiment, the sacrificial structure **120** may be removed by performing a planarization process. For example, the sacrificial structure **120** may be removed by performing one or more chemical mechanical polishing processes, by performing a grinding process, or by performing an etching process, or a combination of such processes. The end result of these operations is a substantially planar surface **105A** which exposes the backside **110** of the IC chips **102** and the exposed conductive portions **108**. FIG. 3E depicts three individual packaged devices **100** after they have been singulated and after the encapsulant material **105** has been trimmed.

[0031] Through use of the present invention, the physical space occupied by the packaged device IC **100** may be reduced as compared to prior art packaged IC devices. Since the present invention does not involve the formation of the relatively large conductive bond pads **22** on a carrier **14**, as shown in FIG. 1A, the length and width of the overall packaged IC device **100** may be reduced. For example, as shown in FIG. 2A, the horizontal dimension **111** from the edge of the IC chip **102** to the edge of the encapsulant material **105** may be approximately 0.1-0.4 mm. In contrast, the corresponding dimension **11** for the device **10** shown in FIG. 1A may be approximately 0.5-1.0 mm. Thus, through use of the present invention, the "footprint" of the packaged IC device **100** may be reduced. Additionally, since the illustrative packaged IC device **100** disclosed herein does not comprise a carrier structure, like the carrier **14** depicted in FIG. 1A, it occupies less vertical space, i.e., it is shorter, as compared to prior art packaged IC devices. For example, in one illustrative embodiment, the overall height **113** (see FIG. 2A) of the packaged IC device **100** may range from approximately 0.1-0.5 mm.

[0032] The particular embodiments disclosed above are illustrative only, as the invention may be modified and practiced in different but equivalent manners apparent to

those skilled in the art having the benefit of the teachings herein. For example, the process steps set forth above may be performed in a different order. Furthermore, no limitations are intended to the details of construction or design herein shown, other than as described in the claims below. It is therefore evident that the particular embodiments disclosed above may be altered or modified and all such variations are considered within the scope and spirit of the invention. Accordingly, the protection sought herein is as set forth in the claims below.

1. A device, comprising:
 - an integrated circuit chip comprising an exposed backside surface defining a plane;
 - a plurality of wire bonds that are conductively coupled to said integrated circuit chip, each of said plurality of wire bonds being conductively coupled to a conductive exposed portion having a lowermost surface that is positioned in said plane defined by said backside surface, said lowermost surface of said exposed portion having a generally circular cross-sectional configuration within said plane; and
 - an encapsulant material positioned adjacent said integrated circuit chip and said plurality of wire bonds, wherein a distance from a side of said integrated circuit chip to a side of said encapsulant material ranges from approximately 0.1-0.4 mm and wherein a distance from said backside surface to a top surface of said encapsulant material ranges from approximately 0.1-0.5 mm.
2. The device of claim 1, wherein said integrated circuit chip comprises at least one of a memory device, a microprocessor and an application specific integrated circuit device.
3. The device of claim 1, wherein said wire bonds are comprised of gold.
4. The device of claim 1, wherein said wire bonds are comprised of aluminum.
5. The device of claim 1, wherein said wire bonds are comprised of copper.
6. The device of claim 1, wherein said exposed conductive portions are comprised of aluminum.
7. (canceled)
8. (canceled)
9. (canceled)
10. The device of claim 1, wherein said encapsulant material comprises an epoxy compound, a molding compound or a liquid encapsulant.
11. The device of claim 1, wherein said encapsulant material has a bottom surface that is substantially positioned in said plane.
12. The device of claim 1, wherein said backside surface is a surface that has been subjected to at least one processing operation after said encapsulant material is formed.

13. The device of claim 1, further comprising a conductive structure that is conductively coupled to said exposed conductive portions.

14. The device of claim 13, wherein said conductive structure comprises a printed circuit board, a silicon interposer, a motherboard, flex tape, or a memory module.

15. The device of claim 13, wherein said integrated circuit chip is conductively coupled to said conductive structure by a plurality of conductive balls.

16. A device, comprising:

an integrated circuit chip comprising an exposed backside surface defining a plane;

a plurality of wire bonds that are conductively coupled to said integrated circuit chip, each of said plurality of wire bonds being conductively coupled to a conductive exposed portion, having a lowermost surface that is positioned in said plane defined by said backside surface, said lowermost surface of said exposed portion having a generally circular cross-sectional configuration within said plane;

an encapsulant material positioned adjacent said integrated circuit chip and said plurality of wire bonds, said encapsulant material comprising a bottom surface that is positioned substantially in said plane, wherein a distance from a side of said integrated circuit chip to a side of said encapsulant material ranges from approximately 0.1-0.4 mm and wherein a distance from said backside surface to a top surface of said encapsulant material ranges from approximately 0.1-0.5 mm; and

a conductive structure that is conductively coupled to said exposed conductive portions.

17. The device of claim 16, wherein said integrated circuit chip comprises at least one of a memory device, a microprocessor and an application specific integrated circuit device.

18. The device of claim 16, wherein said wire bonds are comprised of at least one of gold, aluminum and copper.

19. The device of claim 16, wherein said exposed conductive portions are comprised of aluminum.

20. (canceled)

21. (Canceled)

22. (canceled)

23. The device of claim 16, wherein said conductive structure comprises a printed circuit board, a silicon interposer, a motherboard, flex tape, or a memory module.

24. The device of claim 16, wherein said integrated circuit chip is conductively coupled to said conductive structure by a plurality of solder balls.

25.-60. (canceled)

* * * * *